

PRODUCT RELIABILITY REPORT FOR

DS1343

Maxim Integrated Products

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

DS1343

In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport/dsreliability.html.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

AfT = exp((Ea/k)*(1/Tu - 1/Ts)) = tu/ts
AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10-5 eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

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AfV = exp(B*(Vs - Vu))

AfV = Acceleration factor due to Voltage

Vs = Stress Voltage (e.g. 7.0 volts)

Vu = Maximum Operating Voltage (e.g. 5.5 volts)

B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)
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The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

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Fr = X/(ts * AfV * AfT * N * 2)
X = Chi-Sq statistical upper limit
N = Life test sample size
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Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE: MTTF (YRS): 15252 FITS: 7.5

DEVICE HOURS: 122423091 FAILS: 0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60% Ea: 0.7 B: 0 Tu: 25 °C Vu: 5.5 Volts

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

Device Information:

Process: SA E6H, 2P2M,HPVt,PF-Ring,TCZ,ALOCOS:GOI

Passivation: TEOS Oxide-Nitride Passivation

Die Size: 94 x 70 Number of Transistors: 17192

Interconnect: Aluminum / 0.5% Copper

Gate Oxide Thickness: 150 Å

ESD HBM									
DESCRIPTION	DATE	CODE/PRODUCT/	LOT	CONDITION	READ	POIN	QTY	FAILS	FA#
ESD SENSITIVITY	1106	DS1343	ZJ156598AD	JESD22-A114 HBM 500 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1106	DS1343	ZJ156598AD	JESD22-A114 HBM 1000 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1106	DS1343	ZJ156598AD	JESD22-A114 HBM 1500 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1106	DS1343	ZJ156598AD	JESD22-A114 HBM 2000 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1106	DS1343	ZJ156598AD	JESD22-A114 HBM 2500 VOLTS	1	PUL'S	5	0	
					Total:			0	

LATCH-UP								
DESCRIPTION	DATE	CODE/PRODUCT	/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
LATCH-UP I	1106	DS1343	ZJ156598AD	JESD78A, I-TEST 25C 100mA		6	0	
LATCH-UP I	1106	DS1343	ZJ156598AD	JESD78A, I-TEST 25C 250mA		6	0	
LATCH-UP V	1106	DS1343	ZJ156598AD	JESD78A, V-SUPPLY TEST 25C		6	0	
					Total:		0	

OPERATING LIFE			_
DESCRIPTION	DATE CODE/PRODUCT/LOT CONDITION	READPOIN QTY FA	ILS FA#
HIGH TEMP OP LIFE	0925 DS21Q50 WK945230A 125C, 3.5 VOLTS	1000 HRS 77 0	
HIGH TEMP OP LIFE	0947 DS1341 WD048116A 125C, 5.5 VOLTS	192 HRS 77 0	
HIGH TEMP OP LIFE	1022 MAX34405 QD056611A 125C, 3.6 VOLTS	192 HRS 45 0	
HIGH TEMP OP LIFE	1037 DS1340 WD157959A 125C, 5.5 VOLTS	192 HRS 77 0	
HIGH TEMP OP LIFE	1106 DS1343 ZJ156598AD 125C, 5.5 VOLTS	192 HRS 76 0	
		Total: 0	
FAILURE RATE:	MTTF (YRS): 15252 FITS:	7.5	
	DEVICE HOURS: 122423091 FAILS:	0	